

# HiPerDynFRED™ Epitaxial Diode

## ISOPLUS220™

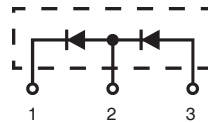
Electrically Isolated Back Surface

$$I_{FAV} = 10 \text{ A}$$

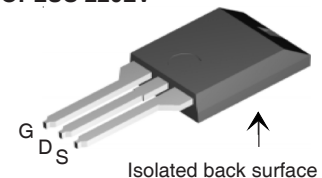
$$V_{RRM} = 800 \text{ V}$$

$$t_{rr} = 30 \text{ ns}$$

| $V_{RRM}^{①}$<br>V | $V_{RRM}$<br>V | Type        |
|--------------------|----------------|-------------|
| 800                | 400            | DSEE 8-08CC |



ISOPLUS 220LV™



### Preliminary Data Sheet

| Symbol     | Conditions                                                                                     | Maximum Ratings    |                  |
|------------|------------------------------------------------------------------------------------------------|--------------------|------------------|
| $I_{FRMS}$ |                                                                                                | 20                 | A                |
| $I_{FAVM}$ | $T_C = 130^\circ\text{C}$ ; rectangular, $d = 0.5$                                             | 10                 | A                |
| $I_{FSM}$  | $T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine                              | 60                 | A                |
| $E_{AS}$   | $T_{VJ} = 25^\circ\text{C}$ ; non-repetitive<br>$I_{AS} = 2 \text{ A}$ ; $L = 180 \mu\text{H}$ | 0.5                | mJ               |
| $I_{AR}$   | $V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive                                  | 0.2                | A                |
| $T_{VJ}$   |                                                                                                | -40...+175         | $^\circ\text{C}$ |
| $T_{VJM}$  |                                                                                                | 175                | $^\circ\text{C}$ |
| $T_{stg}$  |                                                                                                | -40...+150         | $^\circ\text{C}$ |
| $P_{tot}$  | $T_C = 25^\circ\text{C}$                                                                       | 55                 | W                |
| $V_{ISOL}$ | 50/60 Hz RMS; $I_{ISOL} \leq 1 \text{ mA}$                                                     | 2500               | V~               |
| $F_C$      | Mounting force                                                                                 | 11...65 / 2.4...11 | N / lb           |
| Weight     | typical                                                                                        | 2                  | g                |

| Symbol                   | Conditions                                                                                                            | Characteristic Values |                             |
|--------------------------|-----------------------------------------------------------------------------------------------------------------------|-----------------------|-----------------------------|
|                          |                                                                                                                       | typ.                  | max.                        |
| $I_R^{②}$                | $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$<br>$T_{VJ} = 150^\circ\text{C}$ $V_R = V_{RRM}$                           |                       | 60 $\mu\text{A}$<br>0.25 mA |
| $V_F^{③}$                | $I_F = 10 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$<br>$T_{VJ} = 25^\circ\text{C}$                                    |                       | 1.12 V<br>1.53 V            |
| $R_{thJC}$<br>$R_{thCH}$ |                                                                                                                       | 0.6                   | 2.75 K/W<br>K/W             |
| $t_{rr}$                 | $I_F = 1 \text{ A}$ ; $-di/dt = 50 \text{ A}/\mu\text{s}$ ;<br>$V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$     | 30                    | ns                          |
| $I_{RM}$                 | $V_R = 100 \text{ V}$ ; $I_F = 12 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$<br>$T_{VJ} = 100^\circ\text{C}$ | 2                     | 2.4 A                       |

Notes: Data given for  $T_{VJ} = 25^\circ\text{C}$  and per diode unless otherwise specified

① Diodes connected in series

② Pulse test: pulse Width = 5 ms, Duty Cycle &lt; 2.0 %

③ Pulse test: pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

### Features

- Silicon chip on Direct-Copper-Bond substrate
- High power dissipation
- Isolated mounting surface
- 2500V electrical isolation
- Low cathode to tab capacitance (<15pF)
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

### Applications

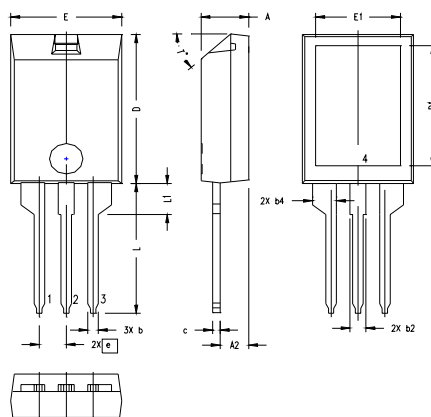
- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

**Recommended replacement:**  
**DPG 10P400PJ**

## ISOPLUS220LV Outline



| SYM | INCHES     |      | MILLIMETERS |       |
|-----|------------|------|-------------|-------|
|     | MIN        | MAX  | MIN         | MAX   |
| A   | .157       | .197 | 4.00        | 5.00  |
| A2  | .098       | .118 | 2.50        | 3.00  |
| b   | .035       | .051 | 0.90        | 1.30  |
| b2  | .049       | .065 | 1.25        | 1.65  |
| b4  | .093       | .100 | 2.35        | 2.55  |
| c   | .028       | .039 | 0.70        | 1.00  |
| D   | .591       | .630 | 15.00       | 16.00 |
| D1  | .472       | .512 | 12.00       | 13.00 |
| E   | .394       | .433 | 10.00       | 11.00 |
| E1  | .295       | .335 | 7.50        | 8.50  |
| e   | .100 BASIC |      | 2.55 BASIC  |       |
| L   | .512       | .571 | 13.00       | 14.50 |
| L1  | .118       | .138 | 3.00        | 3.50  |
| T*  |            |      | 42.5*       | 47.5* |

## NOTE:

1. Bottom heat sink (Pin 4) is electrically isolated from Pin 1, 2, or 3.
2. This drawing will meet dimensional requirement of JEDEC SS Product Outline TO-273 except D and D1 dimension.